

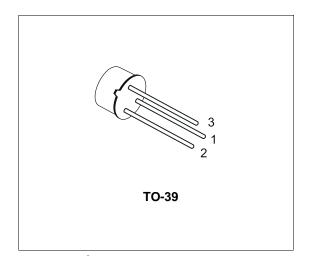
# SILICON NPN TRANSISTORS

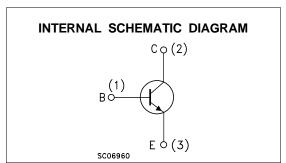
- STMicroelectronics PREFERRED SALESTYPES
- NPN TRANSISTOR

### **DESCRIPTION**

The 2N3439 and 2N3440 are silicon epitaxial planar NPN transistors in jedec TO-39 metal case designed for use in consumer and industrial line-operated applications.

These devices are particularly suited as drivers in high-voltage low current inverters, switching and series regulators.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Va	Value		
		2N3439	2N3440		
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)	450	300	V	
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)	350 250		V	
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	-	7		
Ic	Collector Current	1		Α	
lΒ	Base Current	0.5		Α	
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> ≤ 25 °C	10		W	
P <sub>tot</sub>	Total Dissipation at T <sub>amb</sub> ≤ 50 °C	1		W	
T <sub>stg</sub>	Storage Temperature	-65 to	-65 to 200		
T <sub>i</sub>	Max. Operating Junction Temperature	200		°C	

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#### THERMAL DATA

R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	17.5	°C/W
R <sub>thj-amb</sub>	Thermal Resistance Junction-ambient	Max	175	°C/W

## **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

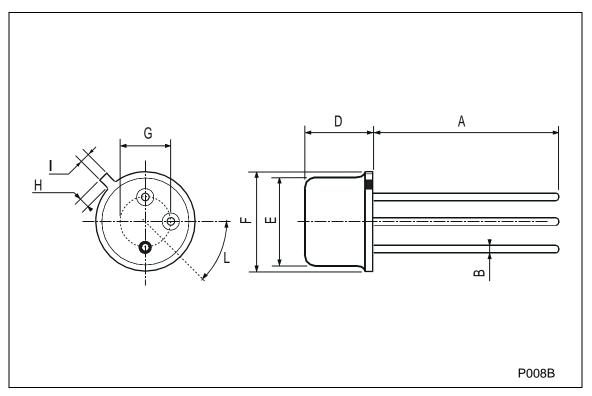
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Ісво	Collector Cut-off Current (I <sub>E</sub> = 0)	for <b>2N3439</b> V <sub>CB</sub> = 360 V for <b>2N3440</b> V <sub>CB</sub> = 250 V			20 20	μΑ μΑ
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	for <b>2N3439</b> V <sub>CE</sub> = 300 V for <b>2N3440</b> V <sub>CE</sub> = 200 V			20 50	μA μA
I <sub>CEX</sub>	Collector Cut-off Current (V <sub>BE</sub> = -1.5V)	for <b>2N3439</b> V <sub>CE</sub> = 450 V for <b>2N3440</b> V <sub>CE</sub> = 300 V			500 500	μA μA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 6 V			20	μΑ
V <sub>CEO(sus)</sub> *	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50 mA for <b>2N3439</b> for <b>2N3440</b>	350 250			V V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	$I_C = 50 \text{ mA}$ $I_B = 4 \text{ mA}$			0.5	V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	$I_C = 50 \text{ mA}$ $I_B = 4 \text{ mA}$			1.3	V
h <sub>FE</sub> *	DC Current Gain	$I_C = 20 \text{ mA}$ $V_{CE} = 10 \text{ V}$ $I_C = 2 \text{ mA}$ $V_{CE} = 10 \text{ V}$ for <b>2N3439</b>	40 30		160	
h <sub>FE</sub>	Small Signal Current Gain	$I_C = 5 \text{ mA}$ $V_{CE} = 10 \text{ V}$ $f = 1 \text{KHz}$	25			
f⊤	Transition frequency	$I_C = 5 \text{ mA}$ $V_{CE} = 10 \text{ V}$ $f = 5 \text{MHz}$	15			MHz

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

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## **TO-39 MECHANICAL DATA**

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	12.7			0.500			
В			0.49			0.019	
D			6.6			0.260	
E			8.5			0.334	
F			9.4			0.370	
G	5.08			0.200			
Н			1.2			0.047	
I			0.9			0.035	
L	45° (typ.)						



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